TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# **TC74VCXH16245FT**

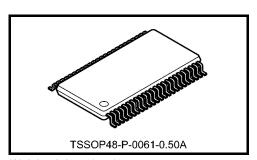
#### Low-Voltage 16-Bit Bus Transceiver with Bushold

The TC74VCXH16245FT is a high-performance CMOS 16-bit bus transceiver. Designed for use in 1.8-V, 2.5-V or 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

This 16-bit bus transceiver is controlled by direction control (DIR) inputs and output enable ( $\overline{\text{OE}}$ ) inputs which are common to each byte. It can be used as two 8-bit transceivers or one 16-bit transceiver. The direction of data transmission is determined by the level of the DIR inputs. The  $\overline{\text{OE}}$  inputs can be used to disable the device so that the busses are effectively isolated.

The A, B data inputs include active bushold circuitry, eliminating the need for external pull-up resisisors to hold unused or floating data inputs at a valid logic level.

All inputs are equipped with protection circuits against static discharge.



Weight: 0.25 g (typ.)

#### Features (Note)

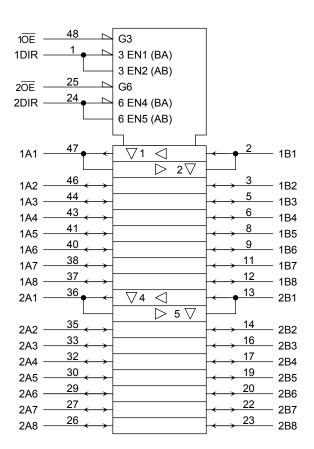
- Low-voltage operation: V<sub>CC</sub> = 1.8 to 3.6 V
- Bushold on data inputs eliminating the need for external pull-up/pull-down resistors
- High-speed operation :  $t_{pd}$  = 2.5 ns (max) ( $V_{CC}$  = 3.0 to 3.6 V)
  - :  $t_{pd}$  = 3.0 ns (max) ( $V_{CC}$  = 2.3 to 2.7 V)
  - $: t_{pd} = 5.0 \text{ ns (max) (V}_{CC} = 1.8 \text{ V)}$
- 3.6-V tolerant control inputs
- Output current : I<sub>OH</sub>/I<sub>OL</sub> = ±24 mA (min) (V<sub>CC</sub> = 3.0 V)
  - $: I_{OH}/I_{OL} = \pm 18 \text{ mA (min)} (V_{CC} = 2.3 \text{ V})$
  - $: I_{OH}/I_{OL} = \pm 6 \text{ mA (min)} (V_{CC} = 1.8 \text{ V})$
- Latch-up performance: -300 mA
- ESD performance: Machine model ≥ ±200 V
  - Human body model ≥ ±2000 V
- Package: TSSOP

Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result.

#### Pin Assignment (top view)

#### 1DIR 10E 48 1B1 47 1A1 1B2 3 46 1A2 GND 4 45 **GND** 1B3 5 1A3 6 1B4 43 1A4 $V_{CC}$ 7 42 $V_{CC}$ 1B5 8 1A5 41 9 1B6 40 1A6 GND 10 39 **GND** 1B7 11 38 1A7 1B8 12 37 1A8 2B1 13 36 2A1 2B2 14 35 2A2 GND 15 GND 34 2B3 16 33 2A3 2B4 17 32 2A4 V<sub>CC</sub> 18 31 $V_{CC}$ 2B5 19 30 2A5 2B6 20 29 2A6 GND 21 28 GND 2B7 22 2A7 27 2B8 23 2A8 26 2OE 2DIR 24 25

## **IEC Logic Symbol**



# **Truth Table**

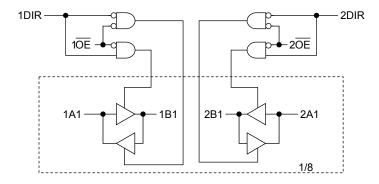
Inp	uts	Fund		
1OE	1DIR	Bus 1A1-1A8	Bus 1B1-1B8	Outputs
L	L	Output	Input	A = B
L	Н	Input Output		B=A
Н	Х	Z		Z

Inp	uts	Fun		
2 <del>OE</del>	2DIR	Bus 2A1-2A8	Bus 2B1-2B8	Outputs
L	L	Output	Input	A = B
L	Н	Input	Output	B = A
Н	Х	Z		Z

X: Don't care

Z: High impedance

# **System Diagram**



#### **Absolute Maximum Ratings (Note 1)**

Characteristics		Symbol	Rating	Unit
Power supply voltage		$V_{CC}$	-0.5 to 4.6	V
	(DIR, OE)		-0.5 to 4.6	
DC input voltage	(An, Bn)	$V_{IN}$	$-0.5$ to $V_{CC}$ + 0.5 (Note 2)	V
DC output voltage	(An, Bn)	V <sub>OUT</sub>	$-0.5$ to $V_{CC} + 0.5$ (Note 3)	V
Input diode current		l <sub>IK</sub>	-50	mA
Output diode current		I <sub>OK</sub>	±50 (Note 4)	mA
Output current		lout	±50	mA
Power dissipation		$P_{D}$	400	mW
DC V <sub>CC</sub> /ground current per supply pin		I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature		T <sub>stg</sub>	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4:  $V_{OUT} < GND$ ,  $V_{OUT} > V_{CC}$ 

#### **Operating Ranges (Note 1) (Note 2)**

Characteristics		Characteristics Symbol		Unit
Device complex selfers		V <sub>CC</sub>	1.8 to 3.6	V
Power supply voltage		v.C.C	1.2 to 3.6 (Note 3)	V
Input voltage	(DIR, $\overline{\text{OE}}$ )	V <sub>IN</sub>	-0.3 to 3.6	V
input voitage	(An, Bn)		0 to V <sub>CC</sub> (Note 4)	V
Output voltage	Output voltage (An, Bn)		0 to V <sub>CC</sub> (Note 5)	V
			±24 (Note 6)	
Output current		I <sub>OH</sub> /I <sub>OL</sub>	±18 (Note 7)	mA
			±6 (Note 8)	
Operating temperature		T <sub>opr</sub>	-40 to 85	°C
Input rise and fall time		dt/dv	0 to 10 (Note 9)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V<sub>CC</sub> or GND. Please connect both bus inputs and the bus outputs with V<sub>CC</sub> or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

Note 2: Floating or unused control inputs must be held high or low.

Note 3: Data retention only

Note 4: OFF state

Note 5: High or low state

Note 6:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 7:  $V_{CC} = 2.3 \text{ to } 2.7 \text{ V}$ 

Note 8:  $V_{CC} = 1.8 \text{ V}$ 

Note 9:  $V_{IN} = 0.8$  to 2.0 V,  $V_{CC} = 3.0$  V



## **Electrical Characteristics**

# DC Characteristics (Ta = -40 to $85^{\circ}$ C, 2.7 V < $V_{CC} \le 3.6$ V)

Characteristi	ics	Symbol	Test C	condition	V <sub>CC</sub> (V)	Min	Max	Unit		
Innut valtage	H-level	V <sub>IH</sub>	-	_	2.7 to 3.6	2.0	_	V		
Input voltage	L-level	V <sub>IL</sub>	-	_	2.7 to 3.6	_	0.8	V		
				I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2	_			
	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -12 mA	2.7	2.2	_			
				I <sub>OH</sub> = -18 mA	3.0	2.4	_			
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	V		
				I <sub>OL</sub> = 100 μA	2.7 to 3.6	_	0.2			
	L-level	\/ - ·	$V_{IN} = V_{IH}$ or $V_{IL}$	\\\.\.\\\.\\\\\\\\\\\\\\\\\\\\\\\\\\\\	I <sub>OL</sub> = 12 mA	I <sub>OL</sub> = 12 mA	2.7	_	0.4	
	L-ievei	V <sub>OL</sub>		I <sub>OL</sub> = 18 mA	3.0	_	0.4			
				I <sub>OL</sub> = 24 mA	3.0	_	0.55			
Input leakage current (DIR, $\overline{OE}$ )		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.7 to 3.6	_	±5.0	μА		
Bushold input minimun	n drive hold		V <sub>IN</sub> = 0.8 V		3.0	75	_	Δ.		
current		I <sub>I</sub> (HOLD)	V <sub>IN</sub> = 2.0 V		3.0	-75	_	μΑ		
Bushold input over-driv	e current to	1	V <sub>IN</sub> = "L"→"H"	V <sub>IN</sub> = "L"→"H"		_	450	^		
change state (Note)			V <sub>IN</sub> = "H"→"L"		3.6	_	-450	μΑ		
3-state output OFF sta	te current	l <sub>OZ</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = V_{CC}$ or GND		2.7 to 3.6	_	±10.0	μА		
Quiescent supply curre	ent	Icc	V <sub>IN</sub> = V <sub>CC</sub> or GND		2.7 to 3.6	_	20.0	μА		
Increase in I <sub>CC</sub> per inp	ut	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	750	μА		

5

Note: It is a necessary electric current to change the input in "L" or "H".



# DC Characteristics (Ta = -40 to 85°C, 2.3 V $\leq$ V<sub>CC</sub> $\leq$ 2.7 V)

Characterist	Characteristics Sy		Test (	Condition		Min	Max	Unit
	T				V <sub>CC</sub> (V)			
Input voltage	H-level	V <sub>IH</sub>		_	2.3 to 2.7	1.6		V
input voltage	L-level	VIL		_	2.3 to 2.7		0.7	V
				I <sub>OH</sub> = -100 μA	2.3 to 2.7	V <sub>CC</sub> - 0.2	_	
	H-level	Voh	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>II</sub>	$I_{OH} = -6 \text{ mA}$	2.3	2.0	_	
				$I_{OH} = -12 \text{ mA}$	2.3	1.8	_	
Output voltage				I <sub>OH</sub> = -18 mA	2.3	1.7	_	V
				$I_{OL} = 100 \mu A$	2.3 to 2.7	_	- 0.2	
	L-level	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 12 mA	2.3		0.4	
				I <sub>OL</sub> = 18 mA	2.3		0.6	
Input leakage current (DIR, $\overline{OE}$ )		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		2.3 to 2.7	_	±5.0	μА
Bushold input minimur	m drive hold		$V_{IN} = 0.7 \ V$		2.3	45	_	
current		I <sub>I</sub> (HOLD)	V <sub>IN</sub> = 1.6 V		2.3	-45	_	μΑ
Bushold input over-drive current to change state (Note)			V <sub>IN</sub> = "L"→"H"		2.7	_	300	
		I <sub>I</sub> (OD)	V <sub>IN</sub> = "H"→"L"		2.7	_	-300	μΑ
3-state output OFF sta	ate current	l <sub>OZ</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = V_{CC}$ or GND		2.3 to 2.7		±10.0	μА
Quiescent supply curre	ent	Icc	$V_{IN} = V_{CC}$ or GND		2.3 to 2.7	_	20.0	μА

6

Note: It is a necessary electric current to change the input in "L" or "H".



## DC Characteristics (Ta = -40 to $85^{\circ}$ C, $1.8 \text{ V} \leq \text{V}_{CC} < 2.3 \text{ V}$ )

Characterist	ics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
Input voltage	H-level	V <sub>IH</sub>		_	1.8 to 2.3	0.7 × V <sub>CC</sub>	_	V
input voitage	L-level	V <sub>IL</sub>		_	1.8 to 2.3		0.2 × V <sub>CC</sub>	V
	H-level	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	$I_{OH} = -100 \mu A$	1.8	V <sub>CC</sub> - 0.2	ı	
Output voltage				$I_{OH} = -6 \text{ mA}$	1.8	1.4		V
	L-level	Vai	V. V. or V.	$I_{OL} = 100 \mu A$	1.8	_	0.2	
	L-level	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	$I_{OL} = 6 \text{ mA}$	1.8	_	0.3	.3
Input leakage current (DIR, $\overline{OE}$ )		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 3.6 V		1.8	_	±5.0	μА
Bushold input minimur	n drive hold	l	V <sub>IN</sub> = 0.36 V		1.8	25	_	^
current		lı (HOLD)	V <sub>IN</sub> = 1.26 V		1.8	-25	_	μΑ
Bushold input over-driv	e current to		V <sub>IN</sub> = "L"→"H"		1.8	_	200	^
change state (Note)		I <sub>I</sub> (OD)	V <sub>IN</sub> = "H"→"L"		1.8	_	-200	μΑ
3-state output OFF sta	te current	l <sub>OZ</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$ $V_{OUT} = V_{CC}$ or GND		1.8		±10.0	μА
Quiescent supply curre	ent	Icc	$V_{IN} = V_{CC}$ or GND		1.8		20.0	μΑ

Note: It is a necessary electric current to change the input in "L" or "H".

## AC Characteristics (Ta = -40 to 85°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF, $R_L = 500$ $\Omega$ ) (Note 1)

Characteristics	Symbol	Test Condition		Min	Max	Unit
Characteristics	Cymbol	rest conducti	V <sub>CC</sub> (V)	IVIIII	IVIGX	Onic
	<b>+</b>		1.8	1.5	5.0	
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	$2.5 \pm 0.2$	1.0	3.0	ns
	t <sub>pHL</sub>		$3.3 \pm 0.3$	8.0	2.5	
	4		1.8	1.5	7.5	
3-state output enable time	t <sub>pZL</sub> t <sub>pZH</sub>	Figure 1, Figure 3	$2.5 \pm 0.2$	1.0	4.9	ns
			$3.3\pm0.3$	8.0	3.8	
			1.8	1.5	5.5	
3-state output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	$2.5 \pm 0.2$	1.0	4.2	ns
	t <sub>pHZ</sub>		$3.3\pm0.3$	8.0	3.7	
Output to output skew			1.8	_	0.5	
	t <sub>osLH</sub>	(Note 2)	$2.5\pm0.2$	_	0.5	ns
	tosHL		$3.3 \pm 0.3$	_	0.5	

Note 1: For  $C_L = 50$  pF, add approximately 300 ps to the AC maximum specification.

Note 2: Parameter guaranteed by design.  $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, \, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$ 



# Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.0$ ns, $C_L = 30$ pF)

Characteristics	Cumbal	Test Condition			Tun	Unit
Characteristics	Symbol	rest condition		V <sub>CC</sub> (V)	Тур.	Oill
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (1)	Note)	1.8	0.25	
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (1)	Note)	2.5	0.6	V
-		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (1)	Note)	3.3	8.0	
		$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (1)	Note)	1.8	-0.25	
Quiet output minimum dynamic V <sub>OI</sub>	V <sub>OLV</sub>	$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (1)	Note)	2.5	-0.6	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (1)	Note)	3.3	-0.8	
Quiet output minimum dynamic V <sub>OH</sub>	-	$V_{IH} = 1.8 \text{ V}, V_{IL} = 0 \text{ V}$ (1)	Note)	1.8	1.5	
		$V_{IH} = 2.5 \text{ V}, V_{IL} = 0 \text{ V}$ (1)	Note)	2.5	1.9	V
		$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$ (I	Note)	3.3	2.2	

Note: Parameter guaranteed by design.

# **Capacitive Characteristics (Ta = 25°C)**

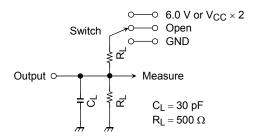
Characteristics	Symbol	Test Condition		Тур.	Unit
Characteristics	Symbol	rest condition	V <sub>CC</sub> (V)	ιyp.	Offile
Input capacitance	C <sub>IN</sub>	_	1.8, 2.5, 3.3	6	pF
Bus I/O capacitance	C <sub>I/O</sub>	_	1.8, 2.5, 3.3	7	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz (Note)	1.8, 2.5, 3.3	20	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/16 \text{ (per bit)}$ 

#### **AC Test Circuit**



Parameter	Switch		
t <sub>pLH</sub> , t <sub>pHL</sub>	Open		
t <sub>pLZ</sub> , t <sub>pZL</sub>	$ \begin{array}{cccccccccccccccccccccccccccccccccccc$		
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND		

Figure 1

#### **AC Waveform**

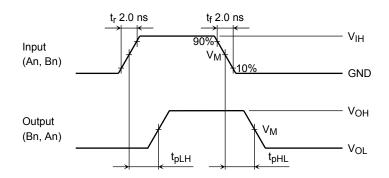


Figure 2  $t_{pLH}$ ,  $t_{pHL}$ 

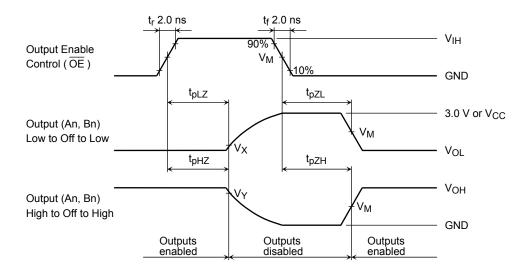


Figure 3  $t_{\text{pLZ}},\,t_{\text{pHZ}},\,t_{\text{pZL}},\,t_{\text{pZH}}$ 

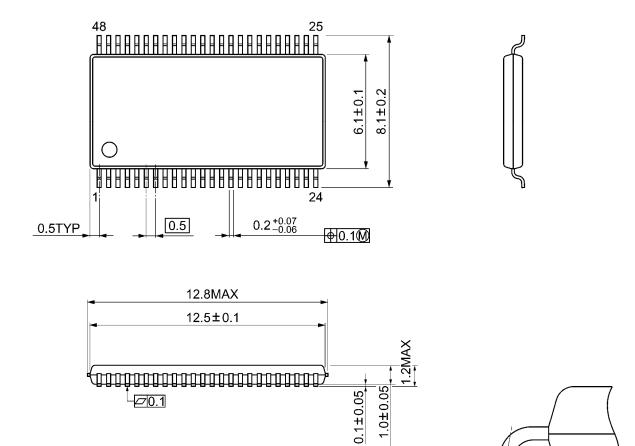
Symbol		V <sub>CC</sub>	-
Syllibol	$3.3\pm0.3~\textrm{V}$	$2.5\pm0.2\textrm{V}$	1.8 V
V <sub>IH</sub>	2.7 V	V <sub>CC</sub>	V <sub>CC</sub>
V <sub>M</sub>	1.5 V	V <sub>CC</sub> /2	V <sub>CC</sub> /2
VX	V <sub>OL</sub> + 0.3 V	V <sub>OL</sub> + 0.15 V	V <sub>OL</sub> + 0.15 V
VY	V <sub>OH</sub> – 0.3 V	V <sub>OH</sub> – 0.15 V	V <sub>OH</sub> – 0.15 V

9

2014-03-01

## **Package Dimensions**

TSSOP48-P-0061-0.50A Unit: mm



 $0.125_{-0.01}^{+0.03}$ 

(0.5)

0.45~0.75

Weight: 0.25 g (typ.)

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